



ELECTRONICS, INC.  
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## NTE2562 (NPN) & NTE2563 (PNP) Silicon Complementary Transistors High Current Switch TO-220 Full Pack

**Description:**

The NTE2562 (NPN) and NTE2563 (PNP) are silicon complementary transistors is a TO-220 full pack type package designed for use as a high current switch. Typical application include relay drivers, high-speed inverters, converters, etc.

**Features:**

- Low Collector-Emitter Saturation Voltage
- High Current Capacity

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

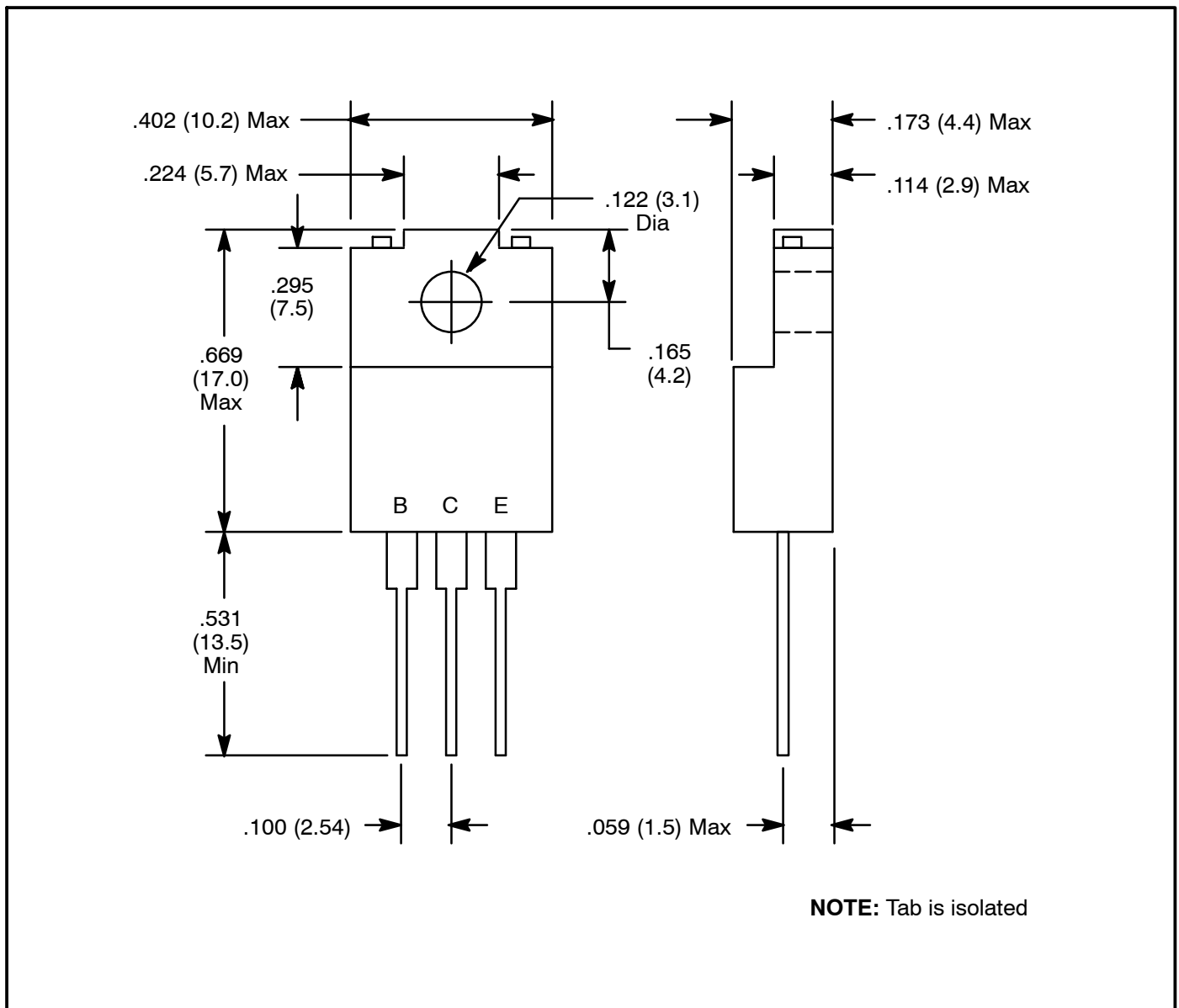
Collector-Base Voltage, $V_{CBO}$ .....	60V
Collector-Emitter Voltage, $V_{CEO}$ .....	30V
Emitter-Base Voltage, $V_{EBO}$ .....	6V
Collector Current, $I_C$	
Continuous .....	12A
Pulse .....	20A
Collector Dissipation, $P_C$	
$T_A = +25^\circ\text{C}$ .....	2W
$T_C = +25^\circ\text{C}$ .....	25W
Operating Junction Temperature, $T_J$ .....	$+150^\circ\text{C}$
Storage Temperature Range, $T_{stg}$ .....	$-55^\circ$ to $+150^\circ\text{C}$

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 40V, I_E = 0$	-	-	0.1	mA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 4V, I_C = 0$	-	-	0.1	mA
DC Current Gain	$h_{FE}$	$V_{CE} = 2V, I_C = 1A$	100	-	200	
		$V_{CE} = 2V, I_C = 6A$	30	-	-	
Current Gain-Bandwidth Product	$f_T$	$V_{CE} = 5V, I_C = 1A$	-	120	-	MHz

**Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Emitter Saturation Voltage NTE2562	$V_{CE(sat)}$	$I_C = 5\text{A}, I_B = 0.25\text{A}$	-	-	0.4	V
NTE2563			-	-	0.5	V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1\text{mA}, I_E = 0$	60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}, R_{BE} = \infty$	30	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1\text{mA}, I_C = 0$	6	-	-	V
Turn-On Time NTE2562	$t_{on}$	$V_{CC} = 10\text{V}, V_{BE} = -5\text{V},$ $10I_{B1} = -10I_{B2} = I_C = 5\text{A},$ Pulse Width = $20\mu\text{s},$ Duty Cycle = 1%	-	0.2	-	$\mu\text{s}$
NTE2563			-	0.1	-	$\mu\text{s}$
Storage Time NTE2562	$t_{stg}$		-	0.5	-	$\mu\text{s}$
NTE2563			-	0.3	-	$\mu\text{s}$
Fall Time	$t_f$		-	0.03	-	$\mu\text{s}$



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